

BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC4061

J-FET INPUT LOW-POWER OPERATIONAL AMPLIFIER

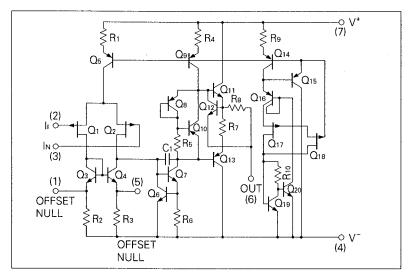
DESCRIPTION

The μ PC4061 is a J-FET input low-power operational amplifier featuring low supply voltage operation from ±2 V. Supply current is ten times smaller than μ PC4081 type J-FET input op-amp. With very low input bias current characteristics, the μ PC4061 is an excellent choice for hand-held measurement equipment and other low-power application circuits.

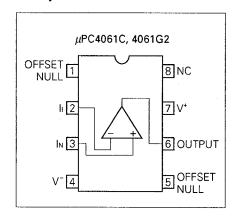
FEATURES

- Low supply current: 220 µA (TYP.)
- Very low input bias and offset currents
- Offset voltage null capability
- High input impedance...J-FET Input Stage
- Low supply voltage operation
- Output short circuit protection
- Internal frequency compensation

EQUIVALENT CIRCUIT



CONNECTION DIAGRAM (Top View)



ORDERING INFORMATION

PART NUMBER	PACKAGE	QUALITY GRADE	
μΡC4061C	8 PIN PLASTIC DIP (300 mil)	Standard	
μPC4061G2	8 PIN PLASTIC SOP (225 mil)	Standard	

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specifications of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

PARA	AMETER	SYMBOL	μPC4061	UNIT
Voltage between V ⁺ and V ⁻ (Note 1)		V+ - V-	-0.3 to +36	V
Differential Input Voltage		Vid	±30	V
Input Voltage (Note 2)		Vi	V ⁻ -0.3 to V ⁺ +0.3	V
Output Voltage (Note 3)		Vo	V ⁻ -0.3 to V ⁺ +0.3	V
Power Dissipation	C Package (Note 4)	Рт	350	mW
	G2 Package (Note 5)	F	440	mW
Output Short Circuit Duration (Note 6)			Indefinite	sec
Operating Temperature Range		Topt	-20 to +80	°C
Storage Temperature Range		Tstg	55 to +125	°C

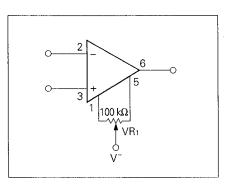
Note 1. Reverse connection of supply voltage can cause destruction.

- **Note 2.** The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.
- **Note 3.** This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.
- Note 4. Thermal derating factor is -5.0 mV / °C when ambient temperature is higher than 55 °C.
- Note 5. Thermal derating factor is -4.4 mV / °C when ambient temperature is higher than 25 °C.
- **Note 6.** Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V±	± 2		± 16	V
Output Current (SOURCE)	IO SOURCE			5	mA
Output Current (SINK)	lo sink			3.5	mA
Capacitive Load $(A_v = +1)$	CL			100	pF

RECOMMENDED OPERATING CONDITIONS

OFFSET VOLTAGE NULL CIRCUIT



CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITION
Input Offset Voltage	Vio		±2	±10	mV	Rs <u>≤</u> 50 Ω
Input Offset Current (Note 7)	lio		±5	±50	рА	
Input Bias Current (Note 7)	Ів		10	100	pА	
Large Signal Voltage Gain	Αυ	3	9		V/mV	$R_L \ge 10 \ k\Omega$, $V_0 = \pm 10 \ V$
Supply Current	lcc		220	250	μA	Io = 0 A
Common Mode Rejection Ratio	CMR	70	90		dB	
Supply Voltage Rejection Ratio	SVR	70	90		dB	
Output Voltage Swing	Vom	±12	+14.0 -13.6		v	R∟ ≥ 10 kΩ
Common Model Input Voltage Range	Vicм	±12	+15 -13		v	
Slew Rate	SR	·	3		V/µs	Av = 1
Unity Gain Frequency	funity		1		MHz	
Input Equivalent Noise Voltage Density	Ðn		30		nV/√Hz	Rs = 100 Ω, f = 1 kHz
Input Offset Voltage	Vio		,	±15	mV	Rs \leq 50 Ω , T _a = -20 to +70 °C
Average Vio Temperature Drift	⊿ Vio/⊿ T		±10		μV/°C	$T_a = -20$ to +70 °C
Input Offset Current (Note 7)	lio			±2	nA	T _a = -20 to +70 °C
Input Bias Current (Note 7)	lв			3.5	nA	Ta = -20 to +70 °C

ELECTRICAL CHARACTERISTICS (Ta = 25 °C, V[±] = ±15 V)

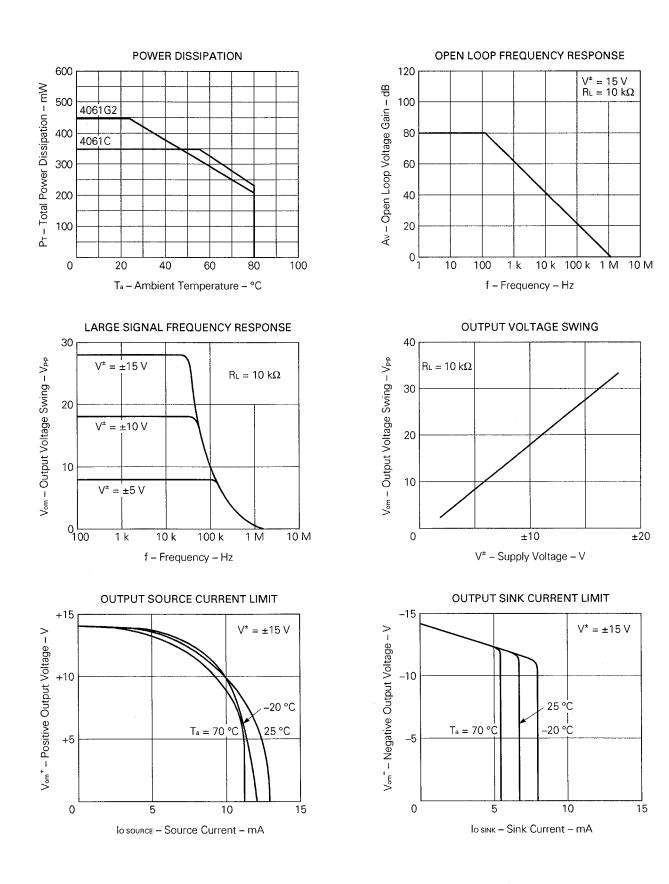
Note 7. Input bias currents flow into IC. Because each currents are gate leak current of P-channel J-FET on input stage.

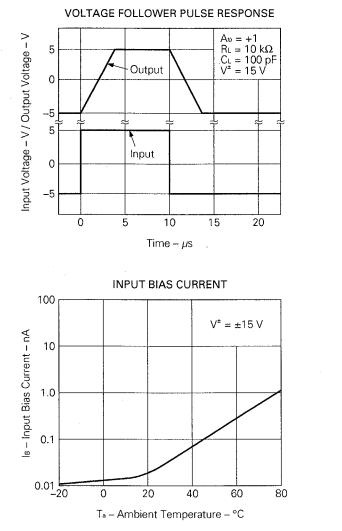
And that are temperature sensitive. Short time measuring method is recommendable to maintain the junction temperature close to the ambient temperature.

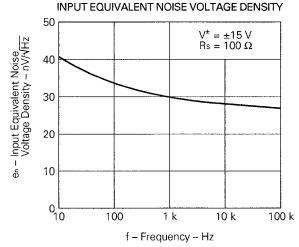
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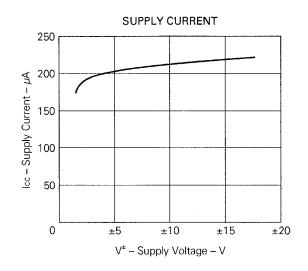
TYPICAL PERFORMANCE CHARACTERISTICS (Ta = 25 °C, TYP.)

NEC

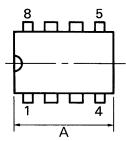


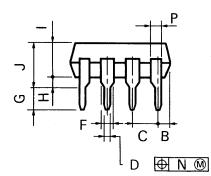


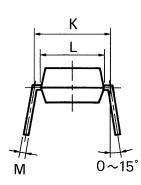




8PIN PLASTIC DIP (300 mil)







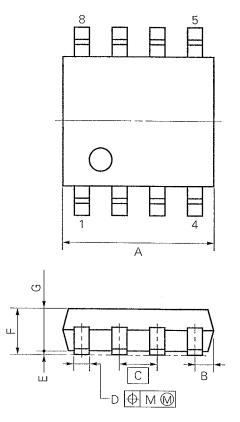
P8C-100-300B,C

NOTES

- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
A	10.16 MAX.	0.400 MAX.
В	1.27 MAX.	0.050 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50 ^{±0.10}	0.020+0.004
F	1.4 MIN.	0.055 MIN.
G	3.2 ^{±0.3}	0.126 ^{±0.012}
н	0.51 MIN.	0.020 MIN.
1	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
к	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
м	0.25 ^{+0.10}	0.010 +0.004
N	0.25	0.01
Р	0.9 MIN.	0.035 MIN.

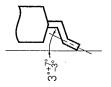
8 PIN PLASTIC SOP (225 mil)

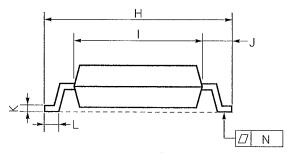


NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

detail of lead end





S8GM-50-225B-2

ITEM	MILLIMETERS	INCHES
А	5.37 MAX.	0.212 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	0.40 ^{+0.10} -0.05	0.016 ^{+0.004} _{-0.003}
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071MAX.
G	1.49	0.059
Н	6.5±0.3	0.256±0.012
I	4.4	0.173
J	1.1	0.043
К	$0.15^{+0.10}_{-0.05}$	0.006 ^{+0.004} 0.002
L	0.6±0.2	$0.024_{-0.009}^{+0.008}$
М	0.12	0.005
N	0.15	0.006

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product. Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI–1207).

[µPC4061G2]

Soldering method	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-001
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15–00–1
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below Number of flow process: 1, Exposure limit*: None	WS15-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

*: Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method."

TYPES OF THROUGH HOLE DEVICE

[µPC4061C]

Soldering method	Soldering conditions	Recommended condition symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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